Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-179-7100

Inclosure Material:	
Metal	
Overall Length:	
0.122 inches	
Overall Diameter:	
0.095 inches	
Internal Configuration:	
Junction contact-darlington connected	
Mounting Method:	
Terminal	
Features Provided:	
Hermetically sealed case	
Voltage Rating In Volts Per Characteris	tic:
15.0 breakdown voltage, collector-to-emi	tter, base open and 7.0 breakdown voltage, emitter to collector, base open and 1.1 collector to
emitter saturation voltage	
Current Rating Per Characteristic:	
0.25 milliamperes repetitive peak forward	current peak
Maximum Operating Tempurature Per N	Measurement Point:
125.0 degrees celsius ambient air	
Terminal Type And Quantity:	
2 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	
Fiig:	
A110a0	